

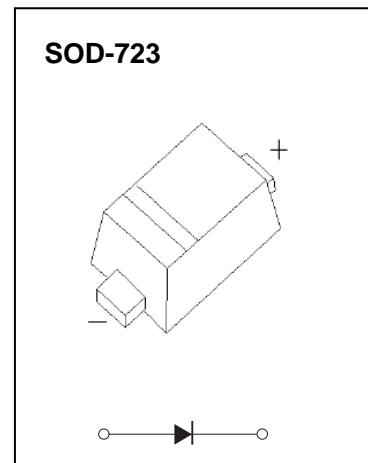


JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOD-723 Plastic-Encapsulate Diodes

RB520G-30 Schottky barrier Diode**FEATURES**

- Small surface mounting type
- Low reverse current and low forward voltage
- High reliability

**MARKING: E****Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C**

Parameter	Symbol	Limit		Unit
DC reverse voltage	V _R	30		V
Mean rectifying current	I _o	100		mA
Peak forward surge current	I _{FSM}	500		mA
Power dissipation	D ₈	100		mW
Thermal Resistance Junction to Ambient	θ _F > ₅	1000		°C/W
Junction temperature	T _j	125		°C
Storage temperature	T _{stg}	-55~+150		°C

Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V _F			0.45	V	I _F =10mA
Reverse current	I _R			0.5	μ A	V _R =10V